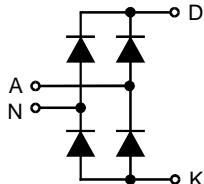


Single Phase Rectifier Bridge

I_{dAVM} = 54 A
V_{RRM} = 800-1600 V

Preliminary data

V _{RSM} V	V _{RRM} V	Type
900	800	VUO 54-08N07
1300	1200	VUO 54-12N07
1500	1400	VUO 54-14N07
1700	1600	VUO 54-16N07



Symbol	Test Conditions	Maximum Ratings	
I _{dAV} ①	T _c = 100°C, module	54	A
I _{fsm}	T _{vj} = 45°C; V _r = 0	300 320	A A
	T _{vj} = T _{vjm} ; V _r = 0	260 280	A A
I ² t	T _{vj} = 45°C; V _r = 0	450 425	A ² s A ² s
	T _{vj} = T _{vjm} ; V _r = 0	340 325	A ² s A ² s
T _{vj}		-40...+150	°C
T _{vjm}		150	°C
T _{stg}		-40...+125	°C
V _{isol}	50/60 Hz, RMS I _{isol} ≤ 1 mA	2500 3000	V~ V~
M _d	Mounting torque (M4)	1.5 - 2 14 - 18	Nm lb.in.
Weight	typ.	18	g

Symbol	Test Conditions	Characteristic Values	
I _R	V _R = V _{RRM} ; V _R = V _{RRM} ; T _{vj} = 25°C; T _{vj} = T _{vjm}	≤ 0.5 ≤ 3	mA mA
V _F	I _F = 55 A; T _{vj} = 25°C	≤ 1.46	V
V _{T0}	For power-loss calculations only	0.8	V
r _T		13	mΩ
R _{thJC}	per diode; DC current	1.1	K/W
	per module	0.28	K/W
R _{thJH}	per diode, DC current	1.6	K/W
	per module	0.4	K/W
d _s	Creeping distance on surface	11.2	mm
d _A	Creepage distance in air	9.7	mm
a	Max. allowable acceleration	50	m/s ²

Data according to IEC 60747 refer to a single diode unless otherwise stated
① for resistive load at bridge output.

IXYS reserves the right to change limits, test conditions and dimensions.

F4 - 18

Features

- Package with DCB ceramic base plate
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

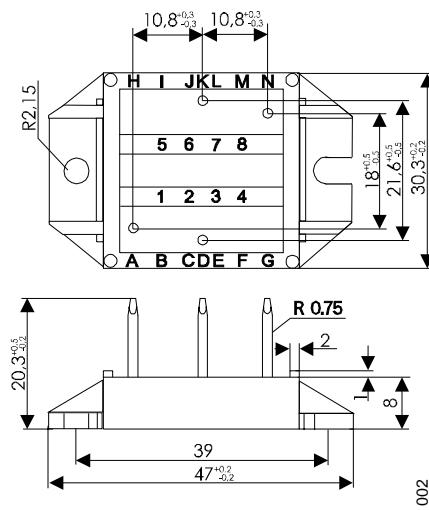
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight

Dimensions in mm (1 mm = 0.0394")



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